

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	20	((source and drain and gate) or transistor or tft) and raman).clm.	US-PGPUB	OR	ON	2007/05/14 12:20
L2	305	257/57-62,66,67,70,72.ccls. and @pd>"20060710"	USPAT	OR	ON	2007/05/14 12:22
L3	342	((thin adj film adj transistor) TFT) and annealing same crystal\$4 and @pd>"20060710"	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/14 12:22
L4	14991	((thin adj film adj transistor) TFT) and @pd>"20060710"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/14 12:23
L5	189	((thin adj film adj transistor) TFT) and annealing same crystalline and @pd>"20060710"	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/14 12:24
L6	0	silicon same (raman adj spectrograph) and @pd>"20060710"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/14 12:24
L7	229	257/61,62,66,67,70,72.ccls. and (distorted grain hydrogen) and @pd>"20060710"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/14 12:25

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